

**1.0A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER
POWERDI**
Product Summary

V_{RRM} (V)	I_O (A)	V_F max (V)	I_R max (μ A)
100	1	0.77	0.35

Features and Benefits

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Patented Interlocking Clip Design for High Surge Current Capacity
- **Lead Free Finish, RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **The DFLS1100Q-7 is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

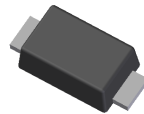
Description and Applications

This Schottky Barrier Rectifier is designed to meet the stringent requirements of automotive applications. It is ideally suited for use as:

- Polarity Protection Diode
- Re-circulating Diode
- Switching Diode

Mechanical Data

- Case: POWERDI[®]123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Band
- Terminals: Finish – Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.01 grams (Approximate)

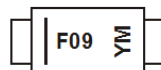


Top View

Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DFLS1100-7	Commercial	POWERDI [®] 123	3000/Tape & Reel
DFLS1100Q-7	Automotive	POWERDI [®] 123	3000/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information


F09 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: B = 2014)
 M = Month (ex: 9 = September)

Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019	2020	2021
Code	A	B	C	D	E	F	G	H	I

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	100	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
RMS Reverse Voltage	$V_{R(RMS)}$	71	V
Forward Current rms ($T_C = +160^\circ\text{C}$, $D = 0.5$)	$I_{F(RMS)}$	2	A
Average Forward Current	$I_{F(AV)}$	1.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I_{FSM}	50	A
Repetitive Peak Reverse Current $t_p = 2\mu\text{s}$, $f = 1\text{kHz}$ Square	I_{RRM}	1.0	A
Repetitive Peak Avalanche Power $t_p = 1\mu\text{s}$, $T_J = +25^\circ\text{C}$	P_{ARM}	1500	W
Non-repetitive Peak Reverse Current $t_p = 100\mu\text{s}$ Square	I_{RSM}	1.0	A
Critical Rate of Rise of Reverse Voltage (Rated V_R , $T_J = +25^\circ\text{C}$)	dV/dt	10000	V/ μs

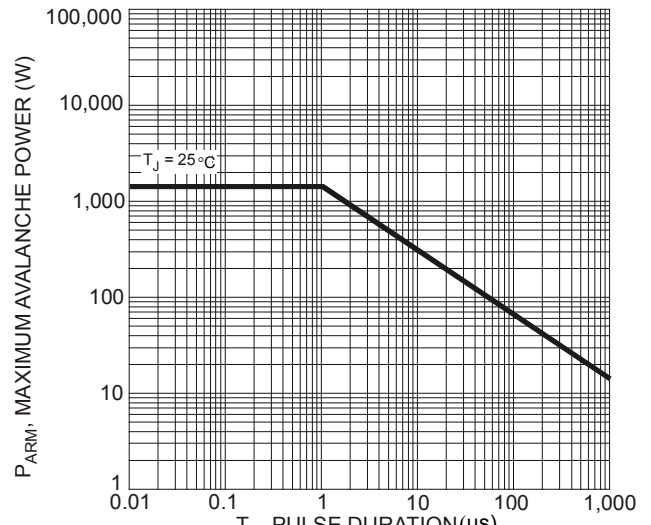
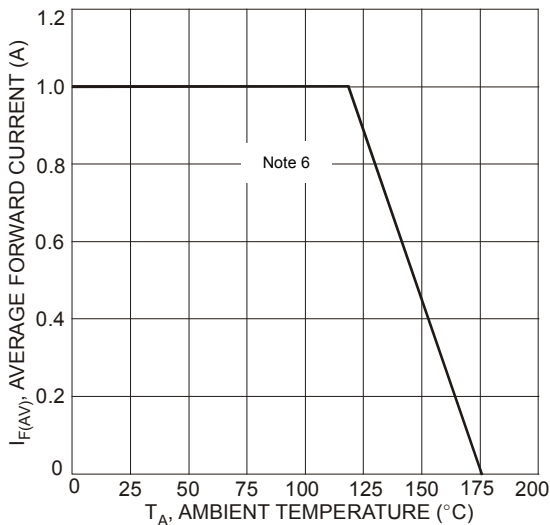
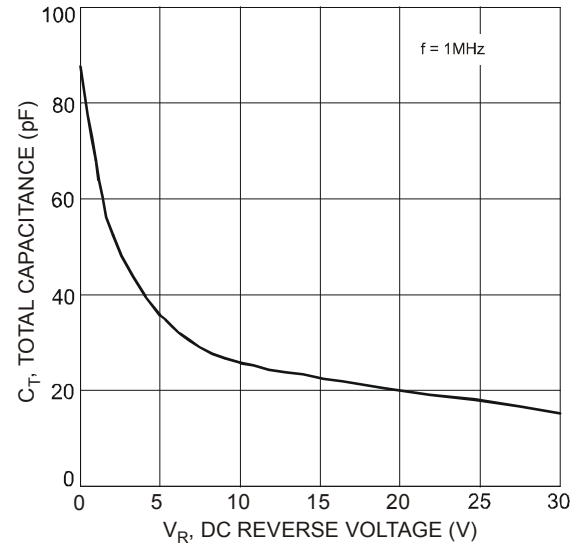
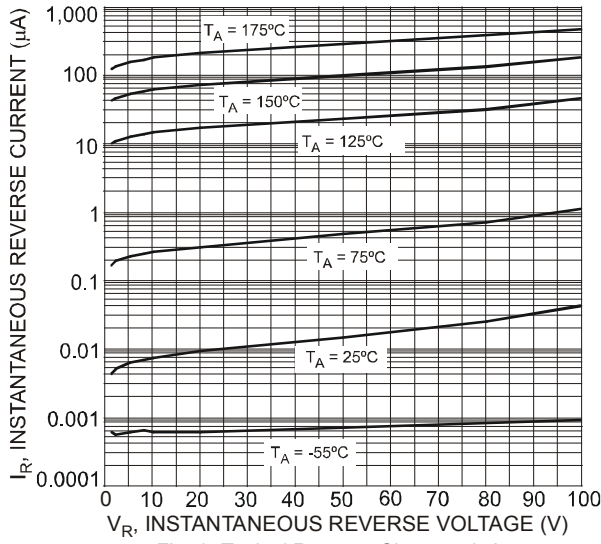
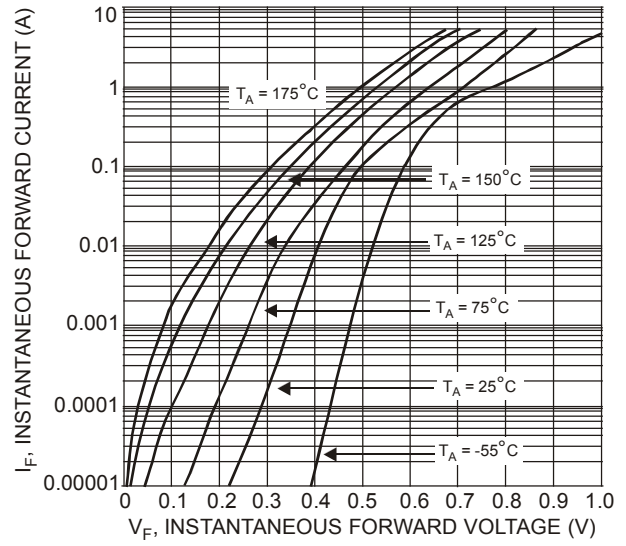
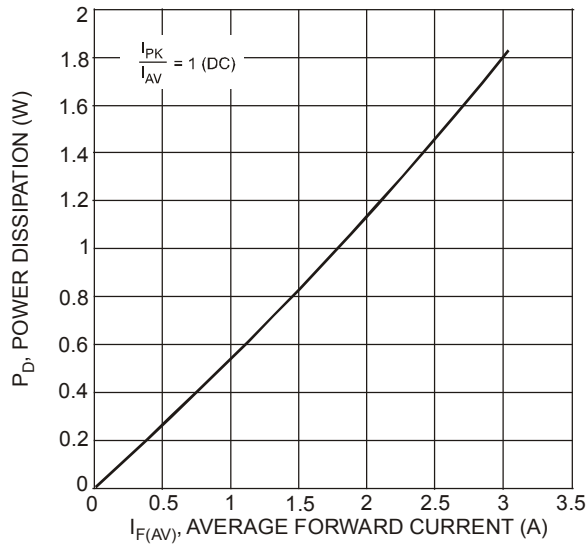
Thermal Characteristics

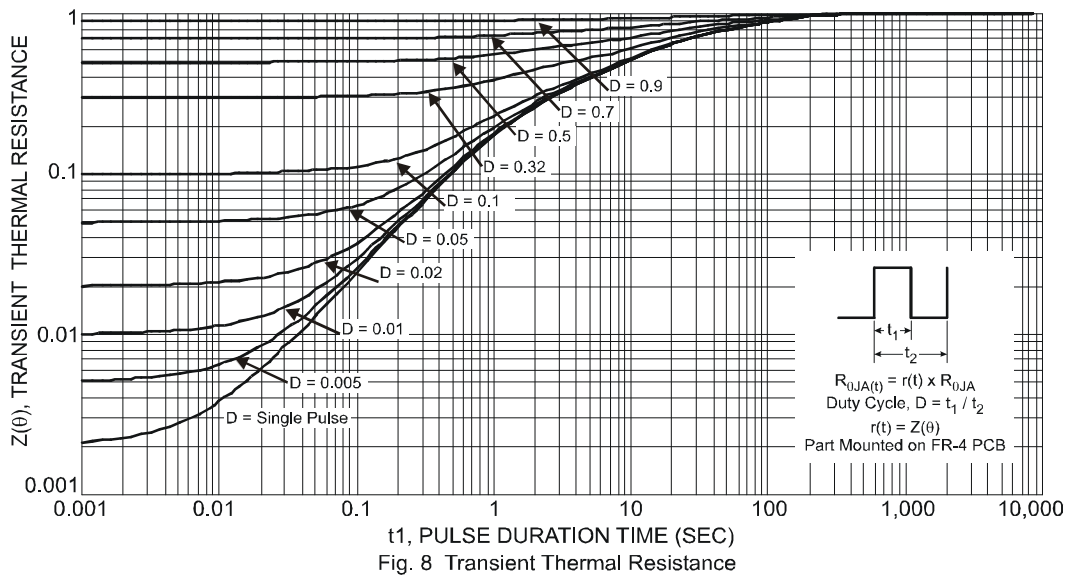
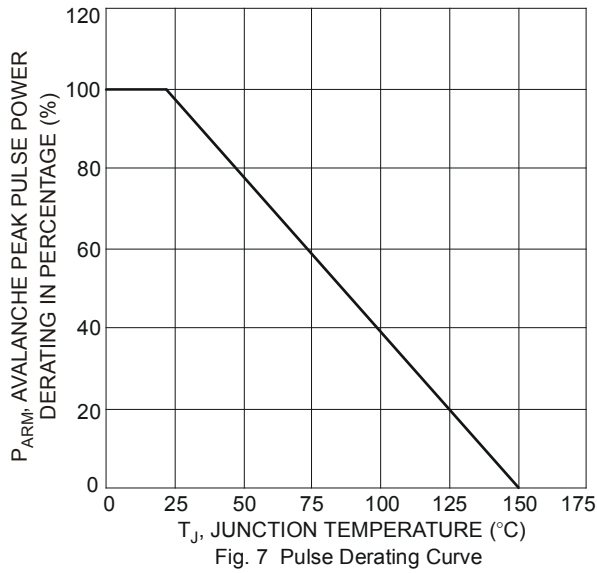
Characteristic	Symbol	Typ	Max	Unit
Thermal Resistance Junction to Soldering (Note 5)	$R_{\theta JS}$	—	7	$^\circ\text{C/W}$
Thermal Resistance Junction to Ambient (Note 6) $T_A = +25^\circ\text{C}$	$R_{\theta JA}$	125	—	
Thermal Resistance Junction to Case (Note 6) $T_A = +25^\circ\text{C}$	$R_{\theta JC}$	21	—	
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +175		$^\circ\text{C}$

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	$V_{(BR)R}$	100	—	—	V	$I_R = 1\text{mA}$
Forward Voltage	V_F	—	—	0.77	V	$I_F = 1.0\text{A}$, $T_A = +25^\circ\text{C}$
		—	0.58	0.62		$I_F = 1.0\text{A}$, $T_A = +125^\circ\text{C}$
		—	—	0.86		$I_F = 2.0\text{A}$, $T_A = +25^\circ\text{C}$
		—	0.65	0.7		$I_F = 2.0\text{A}$, $T_A = +125^\circ\text{C}$
Leakage Current (Note 7)	I_R	—	—	0.10	μA	$V_R = 50\text{V}$, $T_A = +25^\circ\text{C}$
		—	—	3	μA	$V_R = 50\text{V}$, $T_A = +65^\circ\text{C}$
		—	—	15	μA	$V_R = 50\text{V}$, $T_A = +85^\circ\text{C}$
		—	—	0.35	μA	$V_R = 100\text{V}$, $T_A = +25^\circ\text{C}$
		—	—	0.35	mA	$V_R = 100\text{V}$, $T_A = +125^\circ\text{C}$
Total Capacitance	C_T	—	36	—	pF	$V_R = 5\text{V}_{DC}$, $f = 1\text{MHz}$

Notes: 5. Theoretical $R_{\theta JS}$ calculated from the top center of the die straight down to the PCB/cathode tab solder junction.
6. Part mounted on FR-4 board with 2oz., minimum recommended copper pad layout, which can be found on our website at <http://www.diodes.com>.
7. Short duration pulse test used to minimize self-heating effect.
8. The heat generated must be less than thermal conductivity from junction-to-ambient: $dPD/DTJ < 1/R_{thJA}$

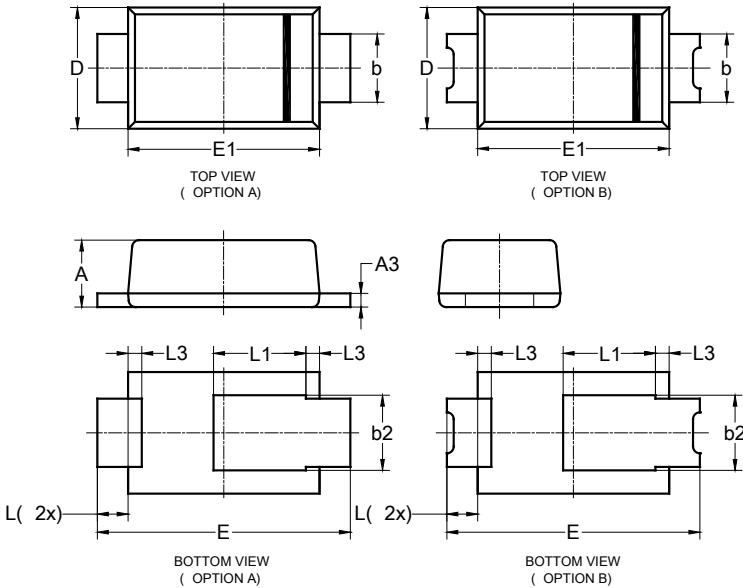




Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI123

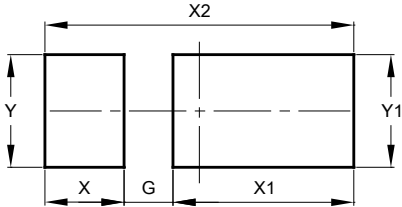


PowerDI123			
Dim	Min	Max	Typ
A	0.93	1.00	0.98
A3	0.15	0.25	0.20
b	0.85	1.25	1.00
b2	1.025	1.125	1.10
D	1.63	1.93	1.78
E	3.50	3.90	3.70
E1	2.60	3.00	2.80
L	0.40	0.50	0.45
L1	1.25	1.40	1.35
L3	0.125	0.275	0.20
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI123



Dimensions	Value (in mm)
G	0.65
X	1.05
X1	2.40
X2	4.10
Y	1.50
Y1	1.50

IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES (“DIODES”) MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes’ websites, harmless against all damages and liabilities.
4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes’ website) under this document.
5. Diodes products are provided subject to Diodes’ Standard Terms and Conditions of Sale (<https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/>) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com